

Features

- SMD LED
- Close responsively to the human eye spectrum
- Light to Current, analog output
- Good output linearity across wide illumination range
- Low sensitivity variation across various light sources

Applications

- Infrared application system
- Optoelectronic automatic control system
- Optoelectronic switch
- Printer
- Counters and sorters
- Encoders
- Floppy disk drive
- Video camera, tape and card readers
- Position sensors

Description

The IN-S1914ATHIRPT is a popular package with versatile design capabilities. It is a PCB type LED which can be used in various applications.the device is matched to visible light and infrared radiation.

Recommended Solder Pattern

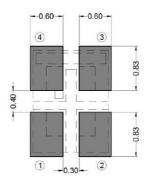
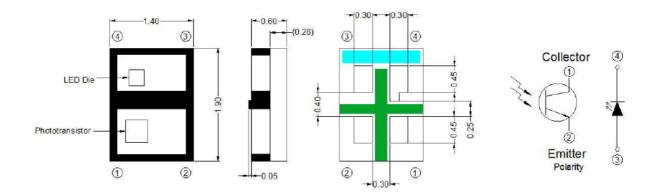


Figure 1. IN-S1914ATHIRPT Solder Pattern



Package Dimensions in mm

Notes.

- 1. All dimensions are in millimeters.
- 2. Tolerance is ± 0.10 mm unless otherwise noted

Figure 2. IN-S1914ATHIRPT Package Dimensions



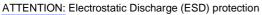
Absolute Maximum Rating at 25°C

Symbol	Parameters	Ratings	Units	Notes					
INPUT (Emitter)									
VR	Reverse Voltage	5	V						
lF	Forward Voltage	100	mA						
IFp	Peak Forward Voltage	500	mA	1					
Pd	Total Power Dissipation	150	mW						
	OUTPUT (Detector)								
BVCEO	BVCEO Collector-Emitter Breakdown Voltage		V	2					
BVECO	Emitter-Collector Breakdown Voltage	5	V	3					
lc	Collector Current	20	mA						
Pd	Total Power Dissipation	75	mW						
Topr	Operating Temperature	-40~+85	°C						
Tstg	Storage Temperature	-40~+100	°C						
Tsol	Soldering Temperature	260	°C	4					
Pto	Total Power Dissipation	150	mW						

Notes

- 1. IFP Conditions--Pulse Width $\leq 100 \mu s$ and Duty $\leq 1\%$.
- 2. Test conditions: Ic=100 μ A, Ee=0mW/cm₂.
- 3. Test conditions: IE=100µA, Ee=0mW/cm2.
- 4. Soldering time \leq 5 seconds.

ESD Precaution





The symbol above denotes that ESD precaution is needed. ESD protection for GaP and AlGaAs based chips is necessary even though they are relatively safe in the presence of low static-electric discharge. Parts built with AllnGaP, GaN, or/and InGaN based chips are STATIC SENSITIVE devices. ESD precaution must be taken during design and assembly. If manual work or processing is needed, please ensure the device is adequately protected from ESD during the process.

Please be advised that normal static precautions should be taken in the handling and assembly of this device to prevent damage or degradation which may be induced by electrostatic discharge (ESD).



Electro-Optical Characteristics

Symbol	Parameters	Test conditions	Min	Тур	Мах	Units	Notes			
INPUT (Emitter)										
VF	Forward Voltage	IF=20mA	-	1.25	1.45	V				
λP	Peak Wavelength	IF=20mA	-	940	-	nm				
lr	Reverse Voltage	VR=5V	-	-	10	uA				
	OUTPUT (Detector)									
VCE(sat)	Collector-Emitter Saturation Voltage	Ic=2mA Ee=1mW/cm2	-	-	0.4	V				
ICEO	Collector Dark Current	VCE=10V Ee=0mW/cm2	-	-	100	nA				
IC(ON)	On State Collector Current	VcE=2V IF=4mA d=1mm	0.16	-	0.35	mA	5			
Ileak	Leakage Current	V _{CE} =2V IF=4mA With no reflection	-	-	1	uA				
tr	Rise Time	Vce=5V, Ic=30mA	-	3	-	uS	6			
tf	Fall Time	RL=50Ω d=1mm	-	3	-	uS	6			

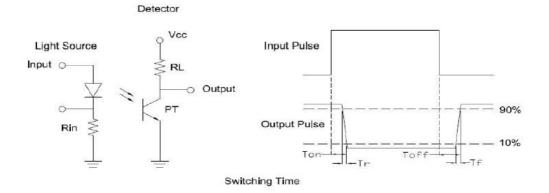
Notes

5. Ic Bin Rank (mA):

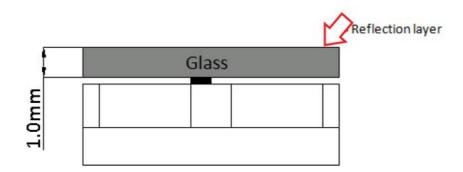
Bin Code	CX
Min	0.16
Max	0.35



6. Test circuit :



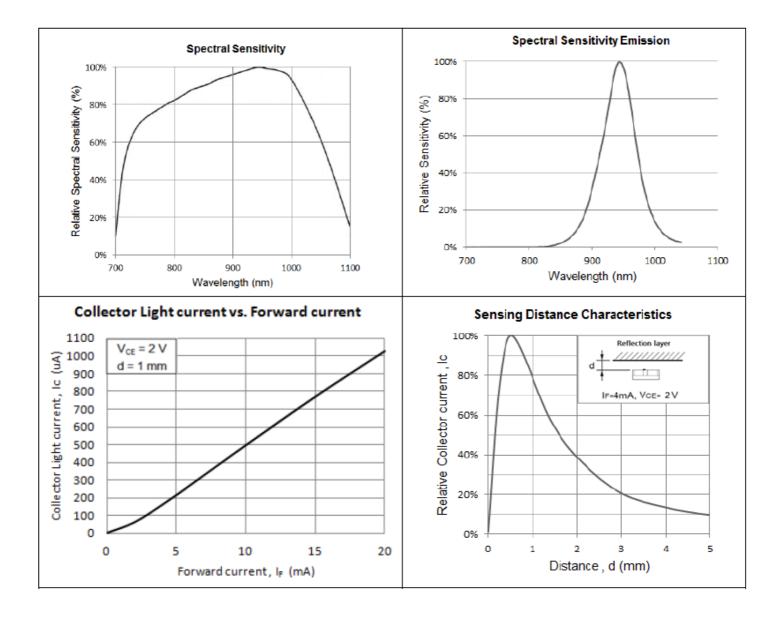
Light Current Measurement Setup Diagram





IN-S1914ATHIRPT Infrared +Phototransistor Top View SMD PCB Type

Typical Characteristic Curves





IN-S1914ATHIRPT Infrared +Phototransistor Top View SMD PCB Type

Ordering Information

Product	Symbol	Parameters	Test conditions	Min	Тур	Max	Units	Orderable Part Number
IN- S1914ATHIRPT	IC(ON)	On State Collector Current	VcE=2V IF=4mA d=1mm	0.16	0.25	0.35	mA	IN- S1914ATHIRPT

Label Specifications



VF:

COLOR BIN:

IV BIN:

QC

Inolux P/N:

Ι	Ν	-	S	1914	А	Т	HIR	РТ	-	-	-	-	-
			Material	Package	Variation	Orientation	Lens	Color				nizec p-off	
	olux ⁄ID		PCB - S	1914 1.9x1.4x		T = Top Mount	HIR =940nm	PT = Photo Transistor					

Lot No.:

Z	2	0	1	7	01	24	001
Internal		Year (2017	2018 \	Month	Date	Serial	
Tracker		fear (2017	, 2018,)	Month	Date	Serial	

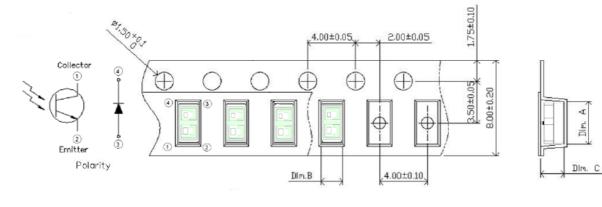


IN-S1914ATHIRPT Infrared +Phototransistor Top View SMD PCB Type

1

Din.

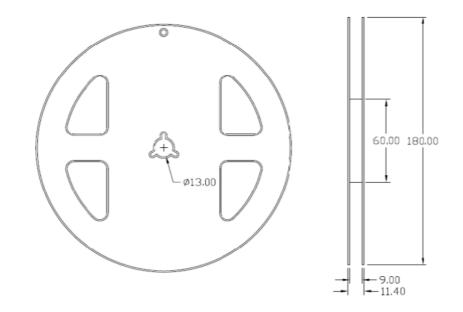
Packaging Information:



Dim. A	Dim. B	Dim. C	Q'ty/Reel
2.18±0.05	1.68±0.05	0.9±0.05	ЗK

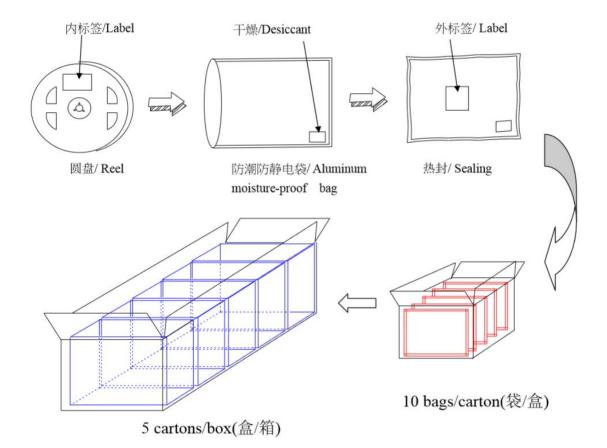
Unit: mm

Reel Dimension





Packing Dimension



5 boxes per carton are available depending on shipment quantity.

	Specification	Material	Quantity				
Carrier tape	Per EIA 481-1A specs	Conductive black tape	3000pcs per reel				
Reel	Per EIA 481-1A specs	Conductive black					
Label	IN standard	Paper					
Packing bag	220x240mm	Aluminum laminated bag/ no-zipper	One reel per bag				
Carton	IN standard	Paper	Non-specified				
Others:							
Each immediate box consists of 5 reels. The 5 reels may not necessarily have the same lot number or the same bin. Each reel has a label identifying its specification; the immediate box consists of a product label as well.							

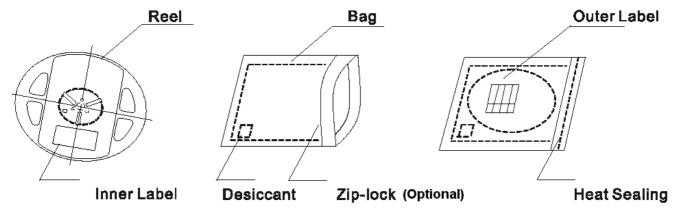


Dry Pack

All SMD optical devices are **MOISTURE SENSITIVE**. Avoid exposure to moisture at all times during transportation or storage. Every reel is packaged in a moisture protected anti-static bag. Each bag is properly sealed prior to shipment.

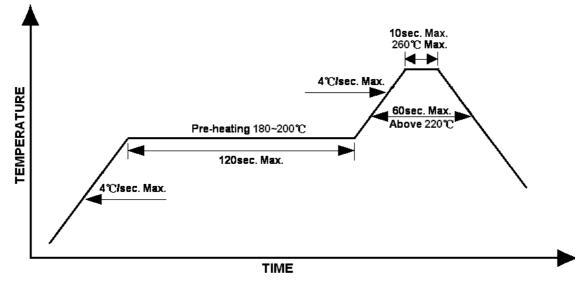
Upon request, a humidity indicator will be included in the moisture protected anti-static bag prior to shipment.

The packaging sequence is as follows:



Reflow Soldering

- Recommended tin glue specifications: melting temperature in the range of 178~192 °C
- The recommended reflow soldering profile is as follows (temperatures indicated are as measured on the surface of the LED resin):



Lead-free Solder Profile



Precautions

- Avoid exposure to moisture at all times during transportation or storage.
- Anti-Static precaution must be taken when handling GaN, InGaN, and AlInGaP products.
- It is suggested to connect the unit with a current limiting resistor of the proper size. Avoid applying a reverse voltage.
- Avoid operation beyond the limits as specified by the absolute maximum ratings.
- Avoid direct contact with the surface through which the LED emits light.
- If possible, assemble the unit in a clean room or dust-free environment.

Reworking

- Rework should be completed within 5 seconds under 260 °C.
- The iron tip must not come in contact with the copper foil.
- Twin-head type is preferred.

Cleaning

Following are cleaning procedures after soldering:

- An alcohol-based solvent such as isopropyl alcohol (IPA) is recommended.
- Temperature x Time should be 50°C x 30sec. or <30°C x 3min
- Ultra sonic cleaning: < 15W/ bath; bath volume ≤ 1liter
- Curing: 100 °C max, <3min

Cautions of Pick and Place

- Avoid stress on the resin at elevated temperature.
- Avoid rubbing or scraping the resin by any object.
- Electro-static may cause damage to the component. Please ensure that the equipment is properly grounded. Use of an ionizer fan is recommended.



Reliability

Item		Standards	Conditions
	failures	Reference	
Description	For all reliability	J-STD-020	1.) Baking at 85°C for 24hrs
Precondition	monitoring tests according		2.) Moisture storage at 85°C/ 60% R.H. for
	to JEDEC Level 2		168hrs
	1Q/ 1/ 22/ 0	JESD22-B102-B	Accelerated aging 155°C/ 24hrs
Solderability		And CNS-5068	Tinning speed: 2.5+0.5cm/s
		010 -00-	Tinning: A: 215°C/ 3+1s or B: 260°C/ 10+1s
		CNS-5067	Dipping soldering terminal only
Resistance to			Soldering bath temperature
soldering heat			A: 260+/-5°C; 10+/-1s
			B: 350+/-10°C; 3+/-0.5s
	1Q/ 1/ 40/ 0	CNS-11829	1.) Precondition: 85°C baking for 24hrs
Operating life test			85°C/ 60%R.H. for 168hrs
			2.) Tamb25°C; IF=20mA; duration 1000hrs
High humidity,	1Q/ 1/ 45/ 0	JESD-A101-B	Tamb: 85°C
high temperature			Humidity: 85% R.H., IF=5mA
bias			Duration: 1000hrs
High temperature	1Q/ 1/ 20	IN specs.	Tamb: 55°C
bias			IF=20mA
Dias			Duration: 1000hrs
	1Q/ 1/ 40/ 0		Tamb25°C, If=20mA,, Ip=100mA, Duty
Pulse life test			cycle=0.125 (tp=125 μ s,T=1sec)
			Duration 500hrs)
	1Q/1/76/0	JESD-A104-A	A cycle: -40 degree C 15min; +85 degree C
-		IEC 68-2-14, Nb	15min
Temperature		,	Thermal steady within 5 min
cycle			300 cycles
			2 chamber/ Air-to-air type
High humidity	1Q/ 1/ 40/ 0	CNS-6117	60+3°C
storage test		-	90+5/-10% R.H. for 500hrs
High temperature	1Q/ 1/ 40/ 0	CNS-554	100+10°C for 500hrs
storage test			
Low temperature	1Q/ 1/ 40/ 0	CNS-6118	-40+5°C for 500hrs
storage test			



Revision History

Changes since last revision	Page	Version No.	Revision Date
Initial Release		1.0	05-10-2021

DISCLAIMER

INOLUX reserves the right to make changes without further notice to any products herein to improve reliability, function or design. INOLUX does not assume any liability arising out of the application or use of any product or circuit described herein; neither does it convey any license under its patent rights, nor the rights of others.

LIFE SUPPORT POLICY

INOLUX's products are not authorized for use as critical components in life support devices or systems without the express written approval of the President of INOLUX or INOLUX CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.

2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.